NSN 5961-01-463-3743

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-463-3743 **Inclosure Material:** Glass **Overall Length:** 5.500 millimeters **Overall Height:** 0.350 millimeters **Overall Width:** 9.500 millimeters **End Application:** 6625-01-425-2551 **Mounting Facility Quantity: Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 4.0 reverse voltage, instantaneous and 4.4 reverse voltage, peak and 0.67 forward voltage, dc and 1.00 forward voltage, dc **Current Rating Per Characteristic:** 50.00 milliamperes service voltage preset and 150.00 milliamperes source cutoff current preset **Capacitance Rating In Picofarads:** Between 0.2 and 0.3 **Maximum Operating Tempurature Per Measurement Point:** -65.0 degrees celsius case and 150.0 degrees celsius case **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No